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June 2014

# FDMC8296

## N-Channel Power Trench® MOSFET

### 30V, 18A, 8.0mΩ

### Features

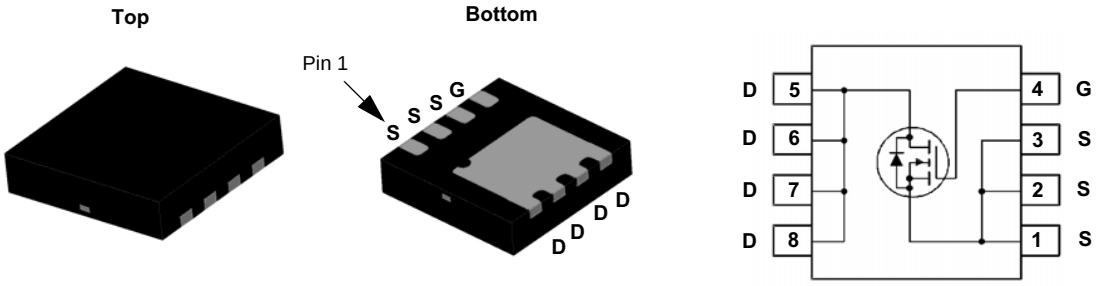
- Max $r_{DS(on)}$ = 8.0mΩ at $V_{GS}$ = 10V, $I_D$ = 12A
- Max $r_{DS(on)}$ = 13.0mΩ at $V_{GS}$ = 4.5V, $I_D$ = 10A
- High performance trench technology for extremely low $r_{DS(on)}$
- Termination is Lead-free and RoHS Compliant

### General Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced Power Trench® process that has been especially tailored to minimize the on-state resistance. This device is well suited for Power Management and load switching applications common in Notebook Computers and Portable Battery Packs.

### Application

- DC - DC Buck Converter
- Notebook battery power management
- Load switch in Notebook




MLP 3.3x3.3

## MOSFET Maximum Ratings $T_A$ = 25°C unless otherwise noted

| Symbol | Parameter | | | Ratings | Units |
|---|---|---|---|---|---|
| $V_{DS}$ | Drain to Source Voltage | | | 30 | V |
| $V_{GS}$ | Gate to Source Voltage | | | ±20 | V |
| $I_D$ | Drain Current -Continuous | $T_C$ = 25°C | | 18 | A |
| | -Continuous | $T_A$ = 25°C | (Note 1a) | 12 | |
| | -Pulsed | | | 52 | |
| $E_{AS}$ | Single Pulse Avalanche Energy | | (Note 3) | 72 | mJ |
| $P_D$ | Power Dissipation | $T_C$ = 25°C | | 27 | W |
| | Power Dissipation | $T_A$ = 25°C | (Note 1a) | 2.3 | |
| $T_{J,}$ $T_{STG}$ | Operating and Storage Junction Temperature Range | | | -55 to +150 | °C |

### Thermal Characteristics

| | | | |
|---|---|---|---|
| $R_{\theta JC}$ | Thermal Resistance, Junction to Case | 4.6 | °C/W |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient (Note 1a) | 53 | |

### Package Marking and Ordering Information

| Device Marking | Device | Package | Reel Size | Tape Width | Quantity |
|---|---|---|---|---|---|
| FDMC8296 | FDMC8296 | MLP 3.3X3.3 | 13 ” | 12 mm | 3000 units |

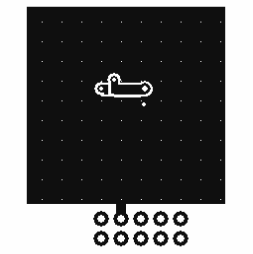
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## Electrical Characteristics $T_J$ = 25°C unless otherwise noted

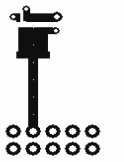
| Symbol | Parameter | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| **Off Characteristics** | | | | | | |
| $BV_{DSS}$ | Drain to Source Breakdown Voltage | $I_D$ = 250μA, $V_{GS}$ = 0V | 30 | | | V |
| $\frac{\Delta BV_{DSS}}{\Delta T_J}$ | Breakdown Voltage Temperature Coefficient | $I_D$ = 250μA, referenced to 25°C | | 17 | | mV/°C |
| $I_{DSS}$ | Zero Gate Voltage Drain Current | $V_{DS}$ = 24V, $V_{GS}$ = 0V, | | | 1 | μA |
| | | $T_J$ = 125°C | | | 250 | |
| $I_{GSS}$ | Gate to Source Leakage Current | $V_{GS}$ = ±20V, $V_{DS}$ = 0V | | | ±100 | nA |
| **On Characteristics** | | | | | | |
| $V_{GS(th)}$ | Gate to Source Threshold Voltage | $V_{GS}$ = $V_{DS}$, $I_D$ = 250μA | 1.0 | 1.9 | 3.0 | V |
| $\frac{\Delta V_{GS(th)}}{\Delta T_J}$ | Gate to Source Threshold Voltage Temperature Coefficient | $I_D$ = 250μA, referenced to 25°C | | -6 | | mV/°C |
| $r_{DS(on)}$ | Static Drain to Source On Resistance | $V_{GS}$ = 10V, $I_D$ = 12A | | 6.5 | 8.0 | mΩ |
| | | $V_{GS}$ = 4.5V, $I_D$ = 10A | | 9.5 | 13.0 | |
| | | $V_{GS}$ = 10V, $I_D$ = 12A, $T_J$ = 125°C | | 9.0 | 12.8 | |
| $g_{FS}$ | Forward Transconductance | $V_{DD}$ = 5V, $I_D$ = 12A | | 44 | | S |
| **Dynamic Characteristics** | | | | | | |
| $C_{iss}$ | Input Capacitance | $V_{DS}$ = 15V, $V_{GS}$ = 0V, f = 1MHz | | 1038 | 1385 | pF |
| $C_{oss}$ | Output Capacitance | | | 513 | 685 | pF |
| $C_{rss}$ | Reverse Transfer Capacitance | | | 87 | 135 | pF |
| $R_g$ | Gate Resistance | f = 1MHz | | 0.9 | | Ω |
| **Switching Characteristics** | | | | | | |
| $t_{d(on)}$ | Turn-On Delay Time | $V_{DD}$ = 15V, $I_D$ = 12A, $V_{GS}$ = 10V, $R_{GEN}$ = 6Ω | | 9 | 18 | ns |
| $t_r$ | Rise Time | | | 3 | 10 | ns |
| $t_{d(off)}$ | Turn-Off Delay Time | | | 19 | 35 | ns |
| $t_f$ | Fall Time | | | 2 | 10 | ns |
| $Q_{g(TOT)}$ | Total Gate Charge | $V_{GS}$ = 0V to 10V, $V_{DD}$ = 15V, $I_D$ = 12A | | 16 | 23 | nC |
| | | $V_{GS}$ = 0V to 4.5V, $V_{DD}$ = 15V, $I_D$ = 12A | | 7.6 | 10.6 | nC |
| $Q_{gs}$ | Total Gate Charge | $V_{DD}$ = 15V, $I_D$ = 12A | | 3 | | nC |
| $Q_{gd}$ | Gate to Drain “Miller” Charge | $V_{DD}$ = 15V, $I_D$ = 12A | | 2.5 | | nC |
| **Drain-Source Diode Characteristics** | | | | | | |
| $V_{SD}$ | Source to Drain Diode Forward Voltage | $V_{GS}$ = 0V, $I_S$ = 12A (Note 2) | | 0.82 | 1.3 | V |
| | | $V_{GS}$ = 0V, $I_S$ = 1.9A (Note 2) | | 0.73 | 1.2 | |
| $t_{rr}$ | Reverse Recovery Time | $I_F$ = 12A, di/dt = 100A/μs | | 25 | 45 | ns |
| $Q_{rr}$ | Reverse Recovery Charge | | | 9 | 18 | nC |

NOTES:

1. $R_{\theta JA}$ is determined with the device mounted on a 1in$^2$ pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.



a. 53 °C/W when mounted on a 1 in$^2$ pad of 2 oz copper



b.125 °C/W when mounted on a minimum pad of 2 oz copper

2. Pulse Test: Pulse Width < 300μs, Duty cycle < 2.0%.

3. $E_{AS}$ of 72 mJ is based on starting T = 25 C, L = 1 mH, $I_{AS}$ = 12 A, $V_{DD}$ = 27 V, $V_{GS}$ = 10 V. 100% test at L = 3 mH, $I_{AS}$ = 5.7 A.

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## Typical Characteristics $T_J$ = 25°C unless otherwise noted

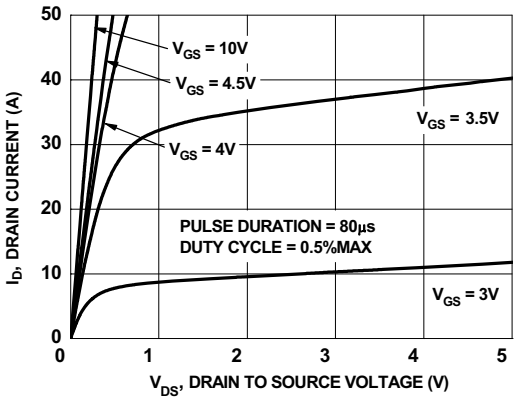



**Figure 1. On-Region Characteristics**

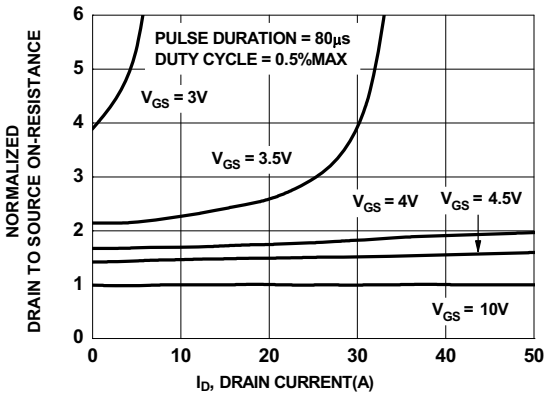



**Figure 2. Normalized On-Resistance vs. Drain Current and Gate Voltage**

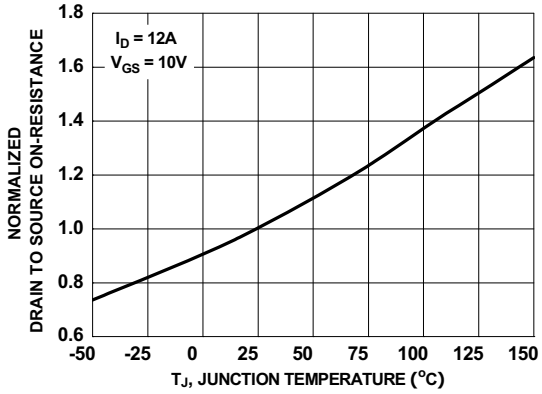



**Figure 3. Normalized On-Resistance vs. Junction Temperature**

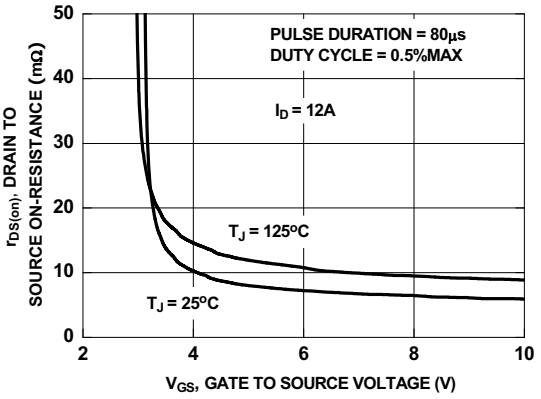



**Figure 4. On-Resistance vs. Gate to Source Voltage**

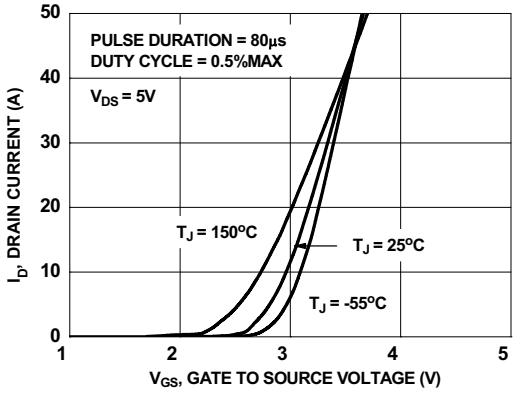



**Figure 5. Transfer Characteristics**

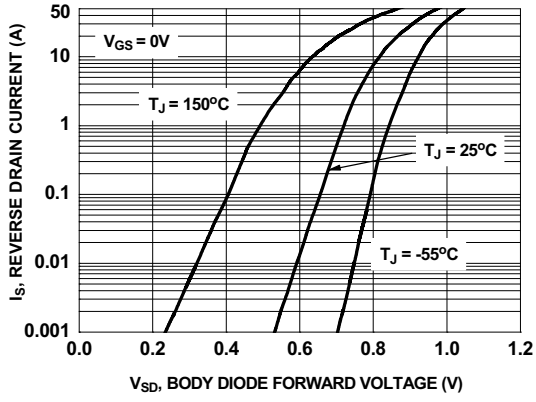



**Figure 6. Source to Drain Diode Forward Voltage vs. Source Current**

## Typical Characteristics $T_J$ = 25°C unless otherwise noted

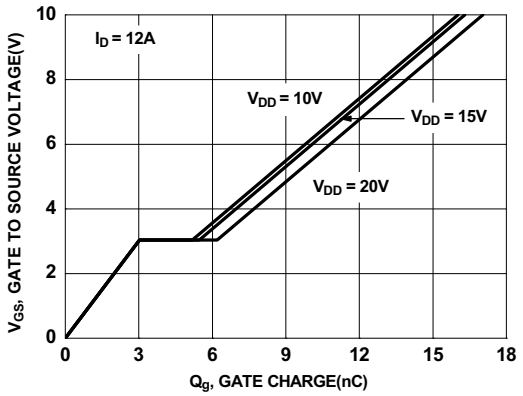



**Figure 7. Gate Charge Characteristics**

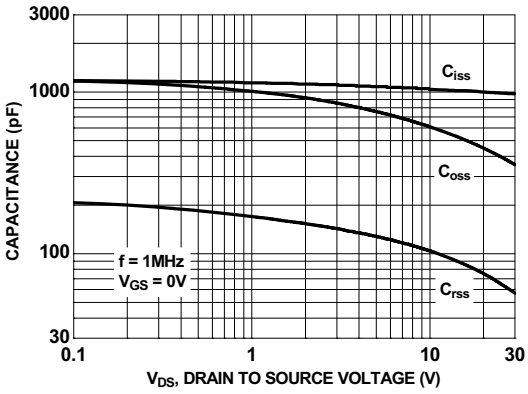



**Figure 8. Capacitance vs. Drain to Source Voltage**

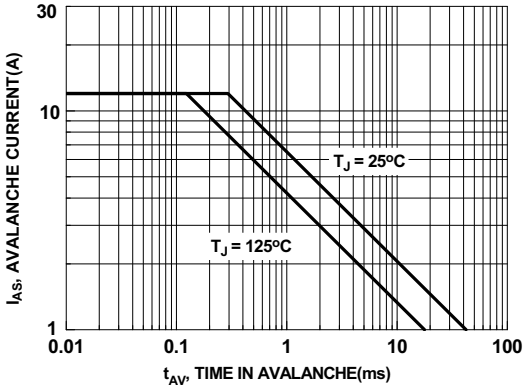



**Figure 9. Unclamped Inductive Switching Capability**

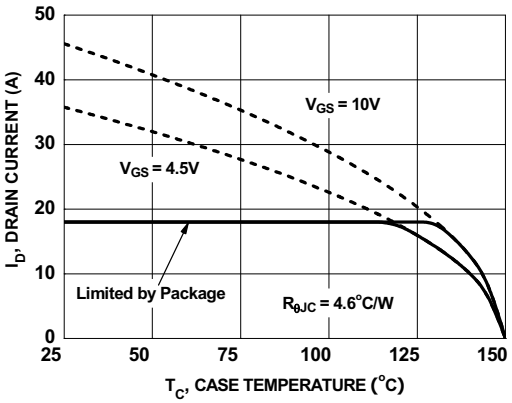



**Figure 10. Maximum Continuous Drain Current vs. Case Temperature**

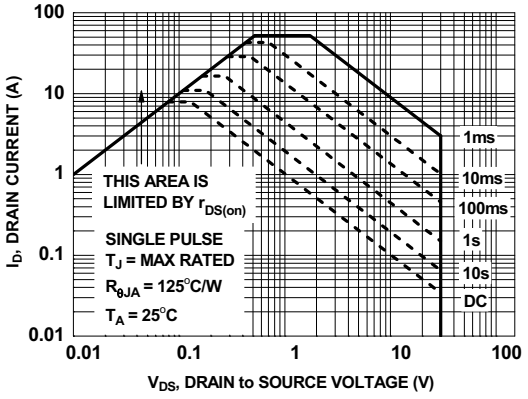



**Figure 11. Forward Bias Safe Operating Area**

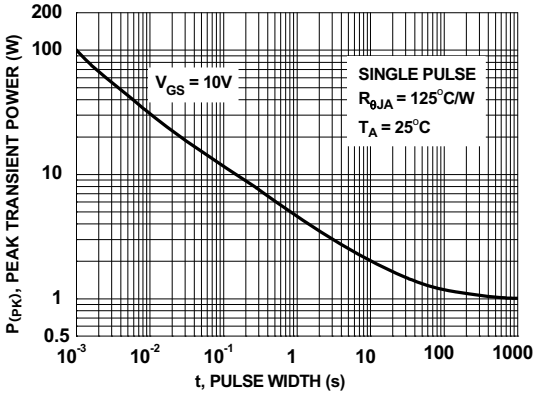



**Figure 12. Single Pulse Maximum Power Dissipation**

## Typical Characteristics $T_J$ = 25°C unless otherwise noted

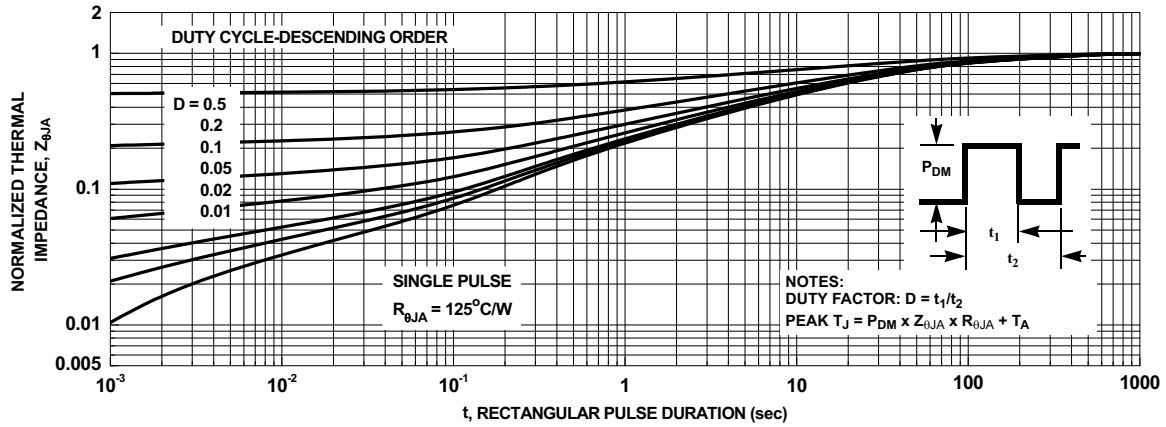
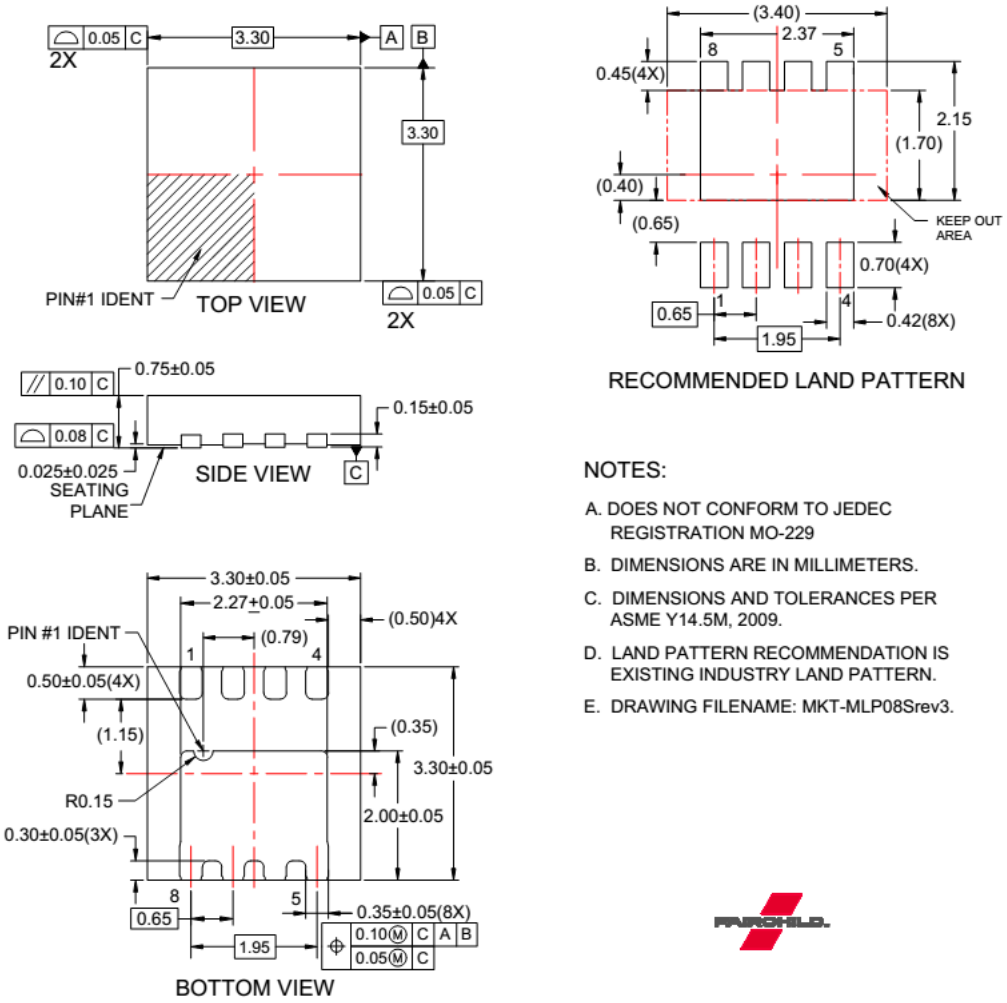



**Figure 13. Transient Thermal Response Curve**

## Dimensional Outline and Pad Layout




NOTES:

A. DOES NOT CONFORM TO JEDEC REGISTRATION MO-229

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 2009.

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